

Enhanced pseudocapacitive energy storage and thermal stability of Sn⁺² ion-intercalated molybdenum titanium carbide (Mo₂TiC₂) MXene

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Supplementary Information

SEM Data:

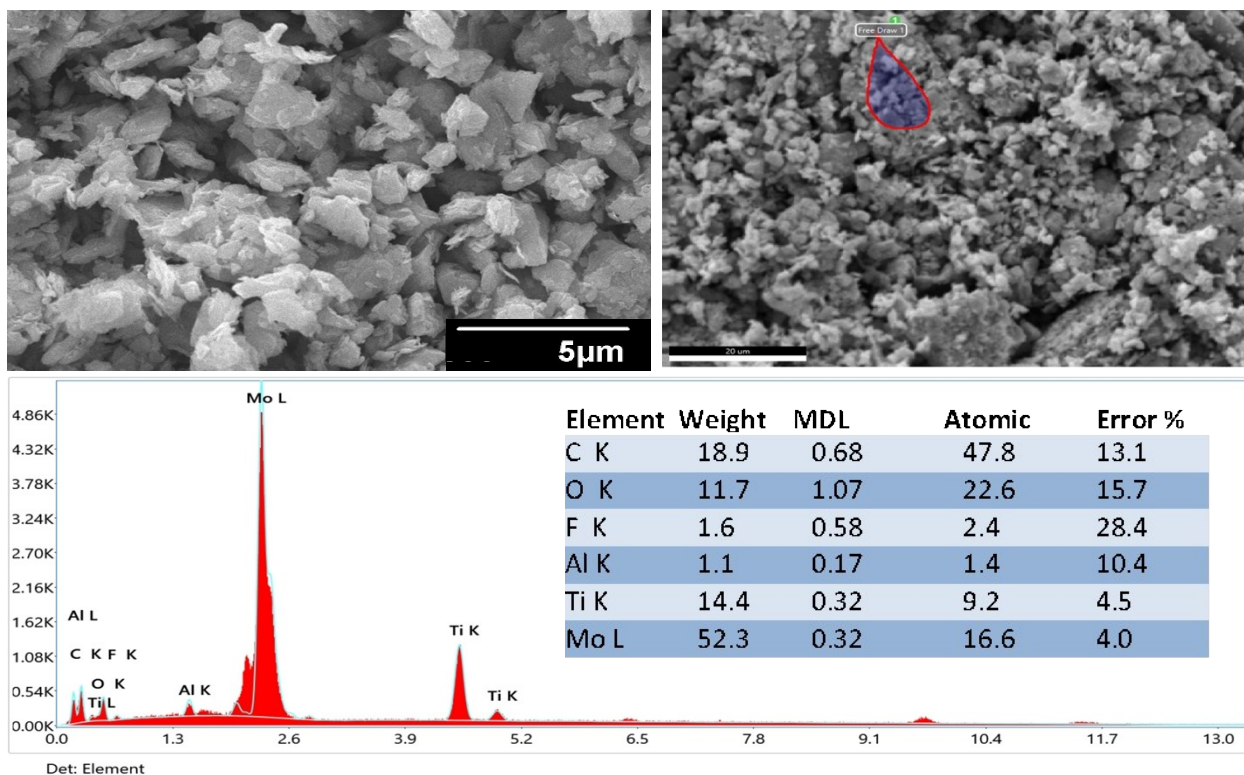


Figure 1: Mo₂TiC₂ MXene SEM image along with their EDX data.

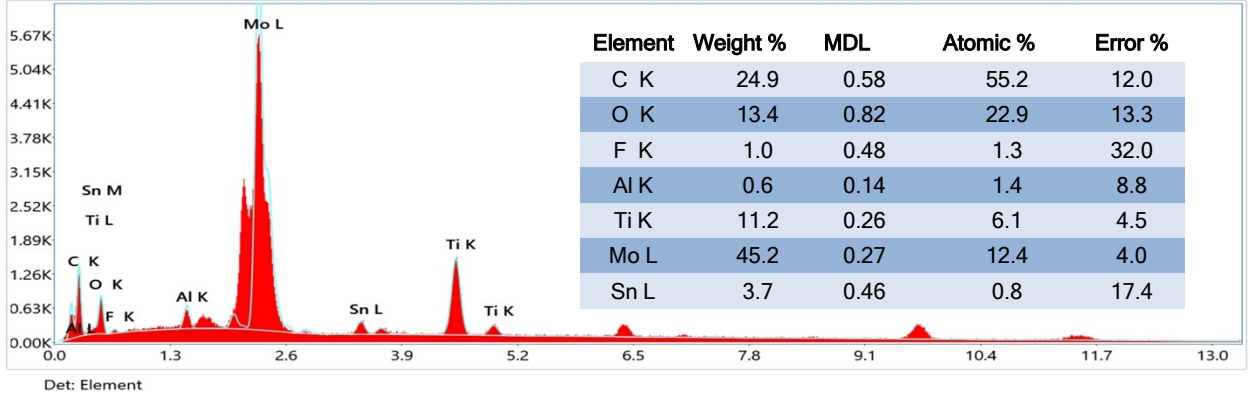
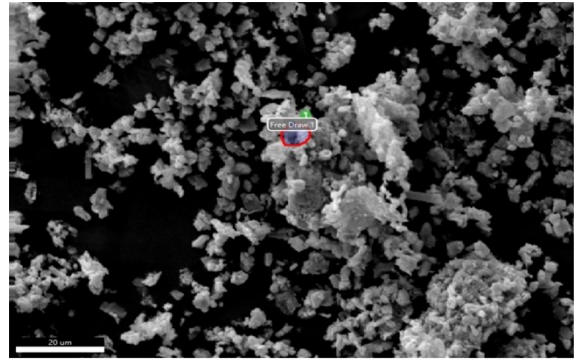
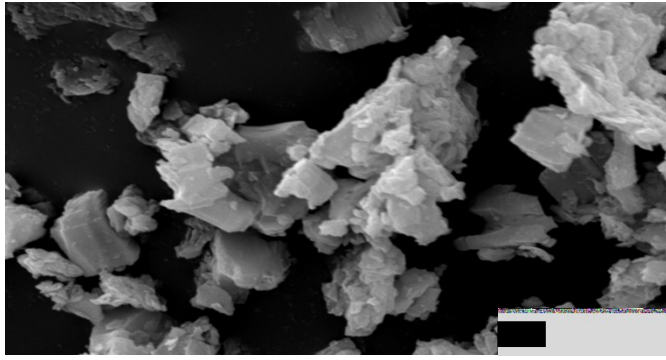


Figure 2: Sn@Mo₂TiC₂ MXene SEM image along with their EDX data.

The dependence of peak value current on scan rate was explained by using the following eq. S11

$$I_p = a.v^b \quad (\text{S11})$$

Here a, b are constants, I_p represents the peak current and v used for scan rate, Generally the value of b=1 (capacitive process) b=0.5 (diffusion control dominated process) but most of the time in case of hybrid energy storage systems the value of b parameter lies between 1 and 0.5, which is evident of combine charge storage mechanism.

The formula used to measure the value of capacitance is written in eq. S12 [1,2]

$$C = \frac{\int I(V)dV}{mv\Delta V} \quad (\text{S12})$$

Here C stands for specific capacitance ($F g^{-1}$), $I(V)dV$ represents the integrated area of CV curve, m used to measure the mass of the active material (g), v stands the scan rate ($mV s^{-1}$) and ΔV represents the voltage window (V).

The eq. S11 can be interpreted in this way by taking log on both sides.

$$\text{Log}(I_p) = \text{Log}(a) + b \log(v) \quad (\text{S13})$$

To study the combine charge storage mechanism further due capacitive process and diffusion control, we used the eq. S14. Here the total peak current I_p is divided into k_1v (capacitive process) and $k_2v^{0.5}$ (diffusion control process) and represents the contribution of charge storage mechanism in both the ways.

$$I_p = k_1v + k_2v^{0.5} \quad (\text{S14})$$

After dividing with $v^{0.5}$ on both sides of eq. S14, hence the obtained eq. S15 basically provides the mathematical base to calculate the values of k_1 & k_2 , which was further utilized to calculate the percentage contributions of diffusion control and capacitive process mechanism.

$$\frac{I_p}{v^{0.5}} = k_1 v^{0.5} + k_2 \quad (\text{SI5})$$

Furthermore, the values of k_1 and k_2 can be determined by plotting a graph between $I/v^{0.5}$ and $v^{0.5}$ [3]. The slop represents the k_1 value and the point of intercept defines the value of k_2 .

Table 1: Comparison of the current study with earlier published data.

Material	Electrolyte	Specific Capacitance (F/g)	References
Ti3C2Tx/PPy nanoparticles 2	1M Na2SO4	184	7
d-Ti3C2 (delaminated layers of Ti3C2)	H2SO4	320	8
Orthorhombic niobium pentoxide (T-Nb2O5)	H2SO4	330	9
Ti3C2Tx/PPy	1M H2SO4	416	10
Ti3C2Tx Aerogels	3M H2SO4	438	11
Nb-doped MXene (Ti3C2)	6M KOH	442	12
Ti3C2Tx/Ag2CrO4	0.1M H2SO4	525	13
Ni-doped Nb2C MXene	1M PVA-H2SO4	666	14
Sn@Mo2TiC2 MXene	1M KOH	670	This work

the eq. (SI6) shows the relationship between real impedance Z_{real} and angular frequency (ω) in low frequency region [4-6].

$$Z_{\text{real}} = R_s + R_{\text{ct}} + \sigma \omega^{-0.5} \quad (\text{SI6})$$

Here σ belong to Warburg factor, which is calculated directly from the slop of the figure 7b. the coefficient of diffusion for K^+ ions can be calculated through following eq.SI7

$$D = \frac{R^2 T^2}{2A^2 n^4 F^4 C^2 \sigma^2} \quad (\text{SI7})$$

Eq. SI7 clarifies the diffusion coefficient is directly proportional to R (gas constant) & T (absolute temperature) and inversely proportional to the A (surface area), n (no. of electrons), F (faraday constant), C (solution concentration) and D (diffusion coefficient).

References

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